# Old Company Name in Catalogs and Other Documents

On April 1<sup>st</sup>, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 20<mark>10</mark> Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)
Send any inquiries to http://www.renesas.com/inquiry.



#### Notice

- 1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
- Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights
  of third parties by or arising from the use of Renesas Electronics products or technical information described in this document.
  No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights
  of Renesas Electronics or others.
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is "Standard" unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
  - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots.
  - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
  - "Specific": Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

# MOS INTEGRATED CIRCUIT $\mu PD5205$

## C-MOS ANALOG MULTIPLEXER

10 M TOM STATE IT

#### **DESCRIPTION**

The  $\mu$ PD5205 is 8-channel C-MOS analog multiplexer. A single-pole 8-position mode and double-pole 4-position mode are settable by 8/4 terminal. TTL/C-MOS compatible input threshold (EN,  $\overline{CS}$ ,  $\overline{WR}$ , RS) make the circuit directly driven by microprocessor. Further advantage each switch has low ON resistance, low leak current and wide analog input range. By these features, the  $\mu$ PD5205 is the optimum choice for data acquisition system.

#### TYPICAL CHARACTERISTICS

- Wide Supply Voltage: 44 V
- Low ON Resistance: 270 Ω TYP. (T<sub>a</sub> = 25 °C)
- Low Source OFF Leak Current: 5 nA MAX. (Ta = 25°C)
- Low Drain ON/OFF Leak Current: 20 nA MAX. (Ta = 25 °C)
- Guaranteed Break-Before-Make Operation

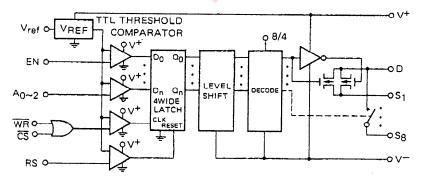
#### **FEATURES**

- A single-pole 8 position mode and double-pole 4 position mode are settable.
- TTL/C-MOS compatible digital input level. (EN, CS, WR, RS)
- Analog input voltage range includes V<sup>+</sup> and V<sup>-</sup>.

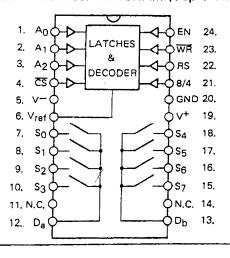
#### ORDERING INFORMATION

Part Number	Package
μPD5205CA	24PIN PLASTIC SHRINK DIP (300 mil)
μPD5205G	24PIN PLASTIC SOP (300 mil)

#### **EQUIVALENT CIRCUIT**



#### CONNECTION DIAGRAM (Top View)



# ABSOLUTE MAXIMUM RATINGS $(T_a=25\,^{\circ}C)$

Supply Voltage between $V^+$ and $V^-$	V+-V-	44	V
Supply Voltage between V <sup>+</sup> and GND	V <sup>+</sup> -GND	25	٧
Supply Voltage between GND and V	GND-V-	25	٧
Input Current (Digital Input and S, D)		30	mΑ
Continuous Current between Source and Drain		20	mA
Peak Current between Source and Drain (Pulsed at 1 ms, 10 % Duty Cycle Max.)		40	mA
Power Dissipation	Pt	570	mW
Operating Temperature	Topt	-20 to +85	°C
Storage Temperature	T <sub>stg</sub>	-55 to +125	°C

# RECOMMENDED OPERATING CONDITIONS ( $T_a=25$ °C)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V±	±8	±15	±16	V
Low Level Logic Input Voltage (at V±=±15 V)	VINL			0.8	V
High Level Logic Input Voltage (at V±=±15 V)	VINH	2.4			٧
Minimum Write Pulse Width (Ta=Topt)	tww	300			ns
Data Settling Time (T <sub>a</sub> =T <sub>opt</sub> )	<sup>t</sup> DW	100			ns
Data Hold Time (Ta=Topt)	tWD	180			ns
Minimum Reset Pulse Width (T <sub>a</sub> =T <sub>opt</sub> )	<sup>t</sup> RS	500			ns

# ELECTRICAL CHARACTERISTICS (V==±15 V, GND=0)

		TYP.		MAX.			
CHARACTERISTIC	SYMBOL	25 °C	-20°C	25 °C	85 °C	UNIT	TEST CONDITIONS
Analog Input Voltage	VANALOG	±15		±15	±15	V	
Drain-Source ON Resistance	R <sub>DS</sub> (ON)	270 230	450 450	450 450	550 550	Ω	V <sub>D</sub> =10 V V <sub>INL</sub> =0.8 V V <sub>INH</sub> =2.4 V I <sub>s</sub> =-200 µA
Drain-Source ON Resistance Matching (Between Channels)	ΔR <sub>DS</sub> (ON)	6				%	$\frac{R_{DS(ON)} MAXR_{DS(ON)} MIN.}{R_{DS(ON)} AVERAGE}$ $-10 V \leq V_{S} \leq 10 V$
Source OFF		-0.005		±5	±50		V <sub>s</sub> =10 V V <sub>D</sub> =−10 V
Current	IS(OFF)	-0,005		±5	±50		V <sub>s</sub> =-10 V V <sub>D</sub> =10 V
Drain OFF		-0.008		±20	+100	nA	V <sub>D</sub> =10 V V <sub>s</sub> =-10 V
Leakage Current	D(OFF)	-0.008		±20	+100		V <sub>D</sub> =-10 V V <sub>s</sub> =10 V
Drain ON		-0.015		±20	+100		VD=Vs(all)=10 V VINL=0.8 V
Leakage Current	ID(ON)	-0.015		±20	+100	nA	VD=Vs(all)=-10 V VINH=2.4 V
High Level		-0.002		-10	-30		V <sub>IN</sub> =2.4 V
Logic Input Current	HNI	0.006		10	30		V <sub>IN</sub> =15 V
Low Level Logic Input Current	INL	-0.002		-10	-30	μА	VIN=0 V
Switching Time of Multiplexer	<sup>t</sup> transition	0.6		1		μs	
Break Before Make Interval	topen	0.2		0.5		μs	
Turn ON Time (EN, WR, CS)	tON	0.5		1		μs	
Turn OFF Time (EN, RS, CS)	tOFF	0.5		1		μς	
Charge Injection	a	20				рC	
OFF Isolation	OIRR	68				dB	VEN=0, R <sub>L</sub> =1 K, C <sub>L</sub> =15 pF, V <sub>\$</sub> =7 V <sub>r.m.s.</sub> , f=500 kHz
Logic Input Capacitance	Cin	2.5				pF	
Source OFF Capacitance	CS(OFF)	5				pF	V <sub>S</sub> =0. V <sub>EN</sub> =0, <del>WR</del> =0, C <sub>S</sub> =0, f≈140 kHz
Drain OFF Capacitance	C <sub>D(OFF)</sub>	12				p,	V <sub>D</sub> =0, V <sub>EN</sub> =0, <del>WR</del> =0, C <sub>S</sub> =0, f=140 kHz

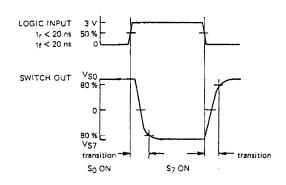
		TYP.		MAX.		UNIT	TEST CONDITIONS
CHARACTERISTIC	SYMBOL	25°C	-20°C	25 °C	85 °C	ONT	TEST CONDITIONS
Positive Supply Current	1+			2.5		mA.	VEN=0, VAX=0
Negative Supply Current	1-			-1.5			V <sub>EN</sub> =0, V <sub>AX</sub> =0

#### Notes:

- Please connect V<sup>-</sup>pin to the minimum voltage level and have a care that V<sup>-</sup>will not go to open or not go to higher than GND pin.
- Please connect N.C. pin (11, 14 pin) to GND in order to improve Off Isolation. 2.
- $\mu PD5205G$  has large chip size. Therefore we recommend hot plate belt conveyer type reflow soldering for mounting. 3. Wave soldering or infrared rays type reflow soldering methods are not recommendable because of their hard heat shock.

## MEASUREMENT CIRCUIT

Fig. 1 Switching Time of Multiplexer



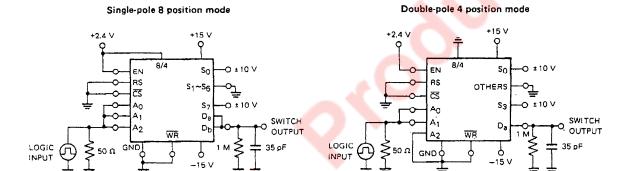
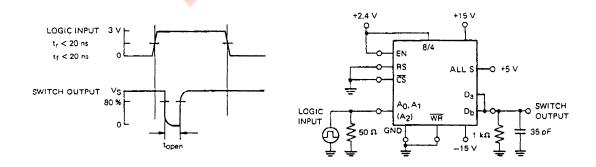


Fig. 2 Brake Before Make Interval



1

Fig. 3 Turn ON/OFF Time of EN

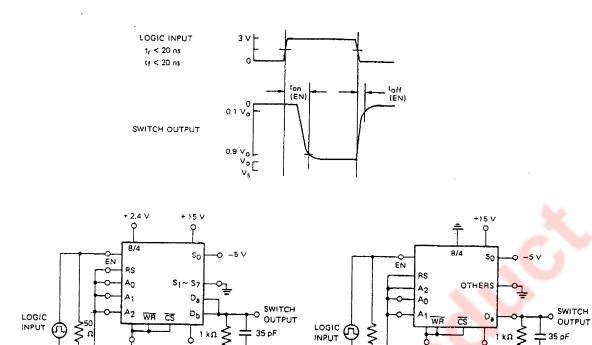


Fig. 4 Turn ON/OFF Time of WR

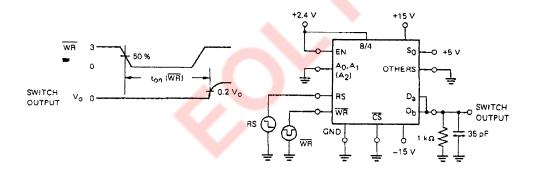


Fig. 5 Turn ON Time of RS

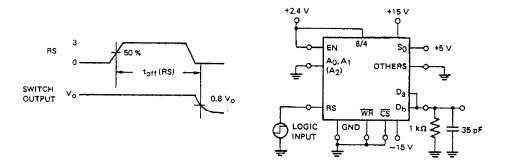


Fig. 6 Turn ON Time of CS

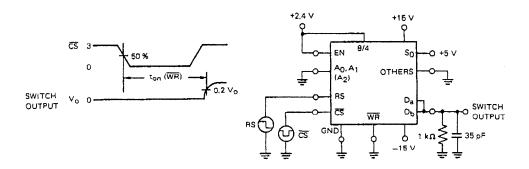
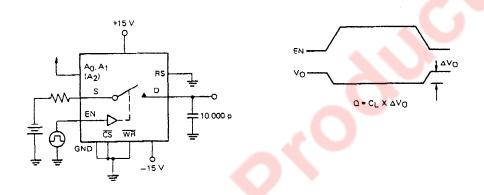


Fig. 7 Charge Injection



# TIMMING CHART

Fig. 8 Data Settling/Hold Time

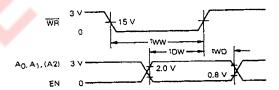
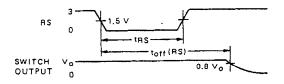


Fig. 9 Reset Pulse Width



# **FUNCTION**

PIN	SYMBOL	FUNCTION			
1	Ao	SW Control Input			
2	A <sub>1</sub>	SW Control Input			
3	A <sub>2</sub>	SW Control Input			
4	<del>CS</del>	Chip Select. Active Low.			
5	V-	Negative supply Voltage (—15 V)			
6	V <sub>ref</sub>	Input threshold Level Control			
7	S <sub>0</sub>	SW Input/Output			
8	S <sub>1</sub>	SW Input/Output			
9	S <sub>2</sub>	SW Input/Output			
10	S <sub>3</sub>	SW Input/Output			
11	N. C.	Non Connection (connect to GND)			
12	Da	SW Input			
13	. D <sub>b</sub>	SW Input			
14	N. C.	Non Connection (connect to GND)			
15	\$7	SW Input/Output			
16	S <sub>6</sub>	SW Input/Output			
17	S <sub>5</sub>	SW Input/Output			
18	S <sub>4</sub>	SW Input/Output			
19	V <sup>+</sup>	Positive Supply Voltage (+15 V)			
20	GND	GND (0 V)			
21	8/4	Mode Control ("H": 8channel, "L": 4channel)			
22	RS	Reset			
23	WR	Write Request. Active Low.			
24	EN	Enable			

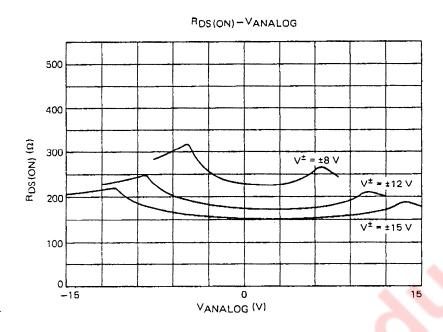
# TRUTH TABLE

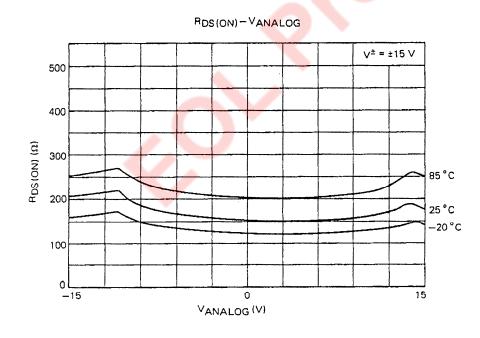
	FNI	0/4				0 [	De		CI	1			ÇI	h 2	
	EN	8/4	A <sub>2</sub>	A1	A <sub>0</sub>	-	RS	0	1	2	3	4	5	6	7
	•	•	•	•	•	5	0		Latch					************	
	•	•	•	•	•	•	1		Latch Clear/SW OFF						
	0	•		•	•	0	0				SW	OFF			
	1	0	•	0	0	0	0	ON				ON			
4 Ch	1	0	•	0	1	0	0		ON				ON		
2	1	0	•	1	0	0	0			ON				ON	
-	1	0	*	1	1	0	0				ON				ON
	1	1	0	0	0	0	Q	ON							
	1	1	0	0	1	0	0		ON						
8	1	1	0	1	0	0	0			ON					
Ch	1	1	0	1	1	0	0				ON				19
1	1	1	1	0	0	0	0					ON			
	1	1	1	0	1	0	0						ON		
	1	1	1	1	0	0	0							ON	
	1	1	1	1	1	0	0								ON

\* Don't Care

After reset, all switches remain off until chip select signal becomes active.

# TYPICAL CHARACTERISTICS (Ta = 25 °C)





# AC CHARACTERISTICS

Photo. 1 Switching Time of Multiplexer ( $V_{ANALOG} = \pm 10 \text{ V}$ )

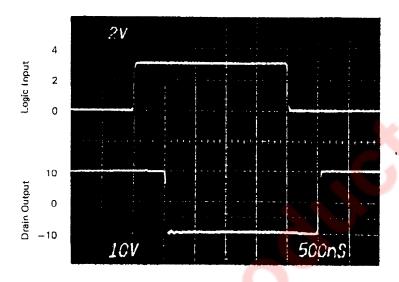


Photo. 2 Brake Before Make Interval (VANALOG = 5 V)

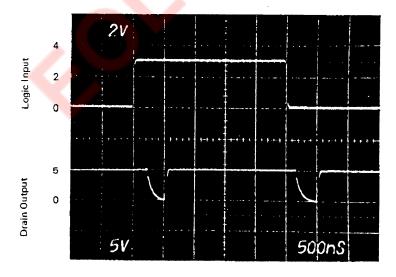


Photo. 3 Switch ON/OFF Time of EN (VANALOG = -5 V)

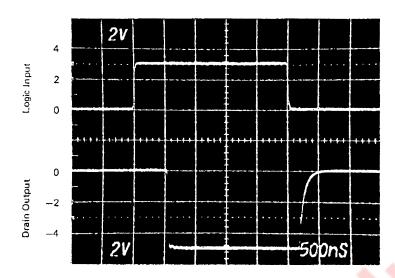


Photo. 4 Switch OFF Time of RS (V<sub>ANALOG</sub> = 5 V)

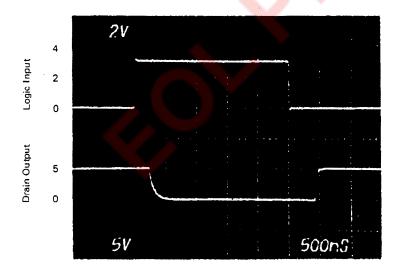
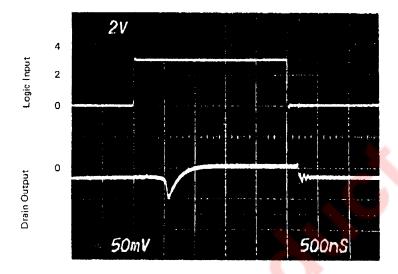


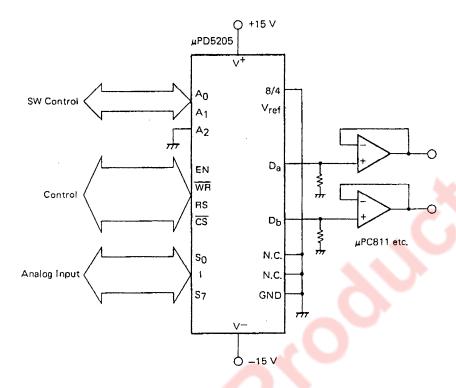
Photo. 5 Charge Injection



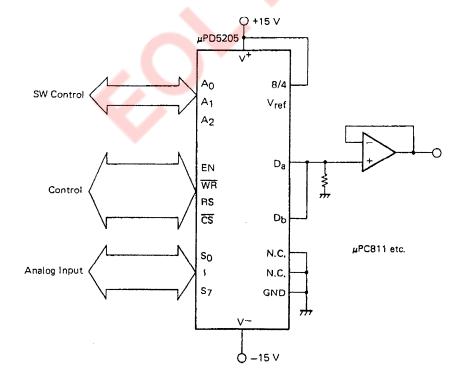
# FD STRUCTURE

# APPLICATION CIRCUIT

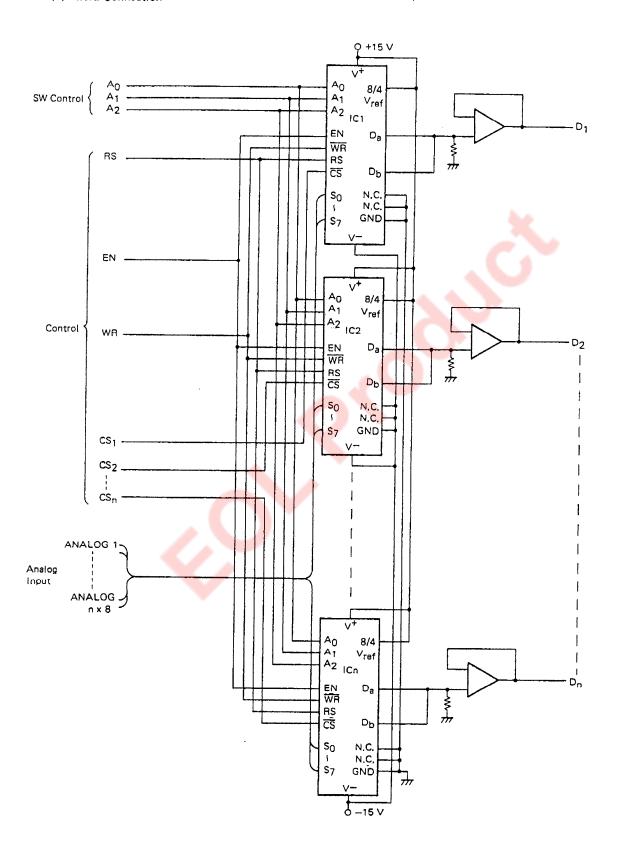
# (1) Double-pole 4position mode



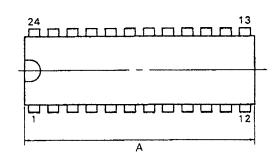
## (2) Single-pole 8position mode

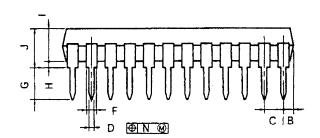


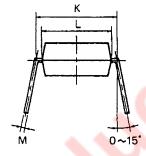
#### (3) Multi Connection



# 24PIN PLASTIC SHRINK DIP (300 mil)







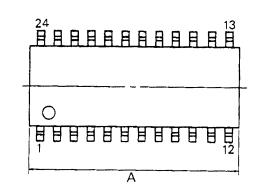
524C-70-3008

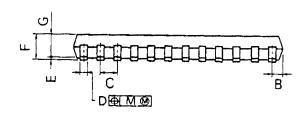
# NOTES

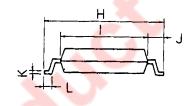
- Each lead centerline is located within 0.17 mm (0.007 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
Α	23.12 MAX.	0.911 MAX.
В	1.78 MAX.	0.070 MAX.
С	1.778 (T.P.)	0.070 (T.P.)
D	0.50 <sup>±0.10</sup>	0.020 +0.004
F	0.85 MIN.	0.033 MIN.
G	3.2 <sup>±0.3</sup>	0.126 <sup>±0.012</sup>
Н	0.51 MIN.	0.020 MIN.
1	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
К	7.62 (T.P.)	0.300 (T.P.)
L	6.5	0.256
М	0.25-8:05	0.010 -0.003
N	0.17	0.007

# 24PIN PLASTIC SOP (300 mil)







## P24GM-50-300B

## NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
Α	15.54 MAX.	0.612 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	0.40 - 0.06	0.016 - 0.004
E	0.1 <sup>±0.1</sup>	0.004 <sup>±0.004</sup>
F	1.8 MAX.	0.071 MAX.
G	1.55	0.061
н	7.7 <sup>±0.3</sup>	0.303 ±0.012
ŀ	5.6	0.220
J	1.1	0.043
К	0.20 -0.05	0.008-0.002
L	0.6 ±0.2	0.024 - 8:889
М	0.12	0.005